TOSHIBA Field Effect Transistor Silicon N Channel Junction Type

# 2SK369

For Low Noise Audio Amplifier Applications

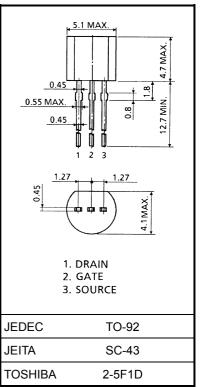
- Suitable for use as first stage for equalizer and MC head amplifiers.
- High  $|Y_{fs}|$ :  $|Y_{fs}| = 40 \text{ mS}$  (typ.) (VDS = 10 V, VGS = 0, IDSS = 5 mA)
- High breakdown voltage:  $V_{GDS} = -40 V (min)$
- Super low noise: NF = 1.0dB (typ.)

 $(V_{DS} = 10 \text{ V}, \text{ ID} = 5 \text{ mA}, \text{ f} = 1 \text{ kHz}, \text{ RG} = 100 \Omega)$ 

• High input impedance:  $I_{GSS} = -1 nA (max) (V_{GS} = -30 V)$ 

### Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Gate-drain voltage	V <sub>GDS</sub>	-40	V
Gate current	۱ <sub>G</sub>	10	mA
Drain power dissipation	PD	400	mW
Junction temperature	Tj	125	°C
Storage temperature range	T <sub>stg</sub>	-55~125	°C



Weight: 0.21 g (typ.)

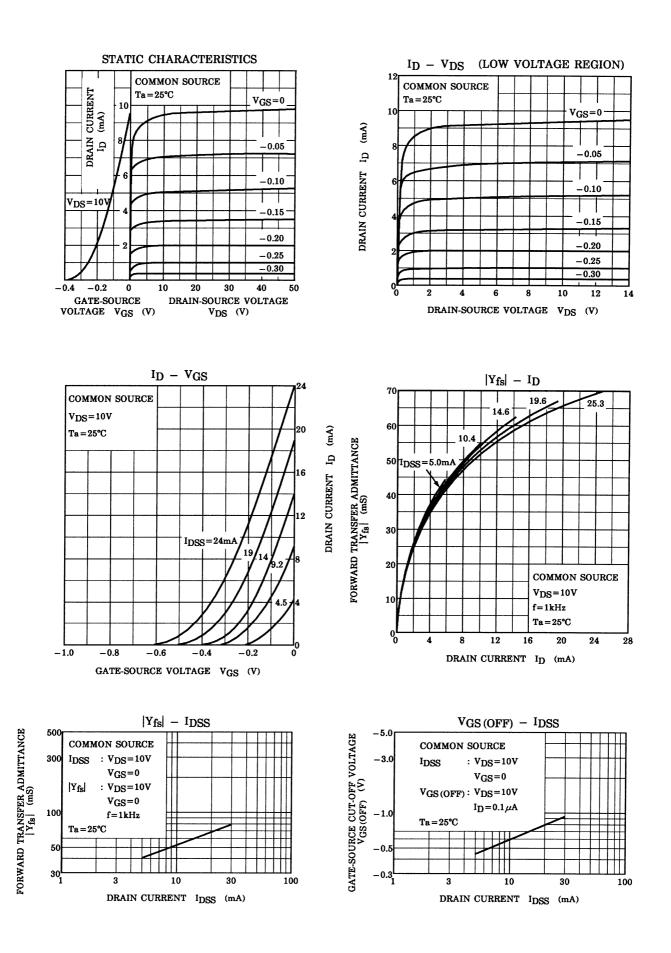
#### Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate cut-off current	I <sub>GSS</sub>	$V_{GS} = -30 V, V_{DS} = 0$		_	-1.0	nA
Gate-drain breakdown voltage	V (BR) GDS	$V_{DS} = 0, I_G = -100 \ \mu A$	-40	_	_	V
Drain current	I <sub>DSS</sub> (Note 1)	$V_{DS} = 10 \text{ V}, \text{ V}_{GS} = 0$	5.0		30	mA
Gate-source cut-off voltage	V <sub>GS (OFF)</sub>	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 0.1 \mu\text{A}$	-0.3	_	-1.2	V
Forward transfer admittance	Y <sub>fs</sub>	$V_{DS} = 10 \text{ V}, \text{ V}_{GS} = 0, \text{ f} = 1 \text{ kHz}, (I_{DSS} = 5 \text{ mA})$	25	40	_	mS
Input capacitance	C <sub>iss</sub>	$V_{DS} = 10 \text{ V}, \text{ V}_{GS} = 0, \text{ f} = 1 \text{ MHz}$	_	75	_	pF
Reverse transfer capacitance	C <sub>rss</sub>	$V_{GD} = -10 V$ , $I_D = 0$ , $f = 1 MHz$	_	15	_	pF
Noise figure (Note 2) —	NF (1)	$\label{eq:VDS} \begin{array}{l} V_{DS} = 10 \; V, \; R_{G} = 100 \; \Omega, \; I_{D} = 5 \; mA, \\ f = 100 \; Hz \end{array}$	—	5	10	dB
	NF (2)	$V_{DS}$ = 10 V, $R_G$ = 100 $\Omega,$ $I_D$ = 5 mA, $f$ = 1 kHz		1	2	

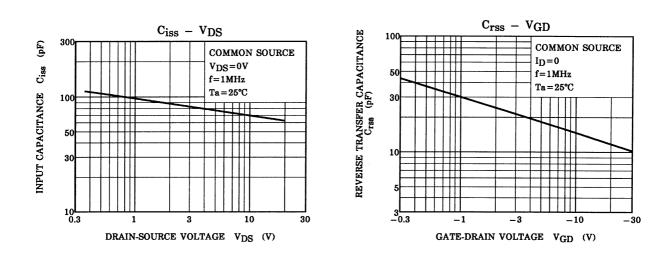
Note 1: I<sub>DSS</sub> classification GR: 5.0~10.0 mA, BL: 8.0~16.0 mA, V: 14.0~30.0 mA

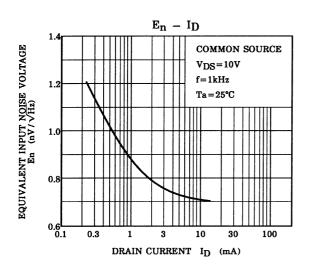
Note 2: Use this in the low voltage region (VDS < 15 V) for low noise applications.

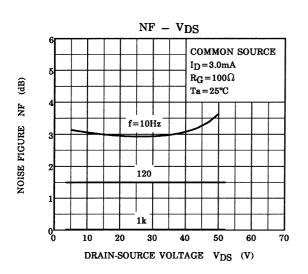
Unit: mm

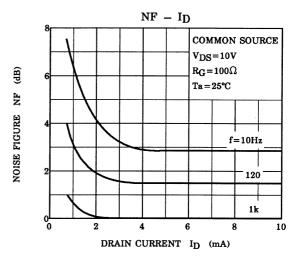


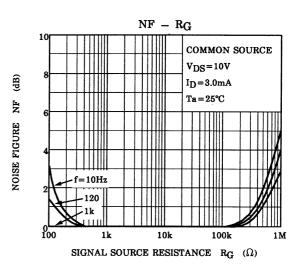
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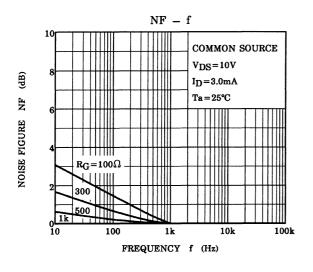


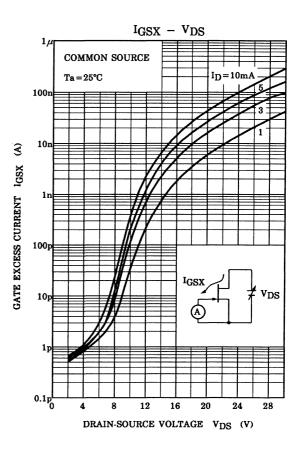


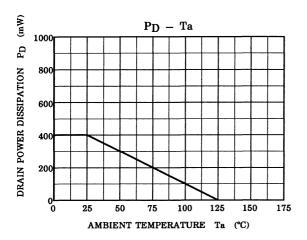




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